

# RV1S9060A

# Data Sheet

R08DS0168EJ0100 Rev.1.00

HIGH CMR, 15Mbps CMOS OUTPUT, LOW FORWARD-CURRENT(IF) 3.3V/5V OPERATION, Jun 4, 2019 5-PIN with 8mm creepage distance package LSO5 PHOTOCOUPLER

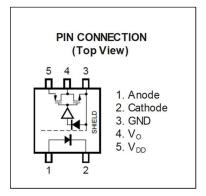
# DESCRIPTION

The RV1S9060A is a photocoupler featuring high-speed switching up to 15Mbps with active low output logic which consist of an AIGaAs LED on the input side and an integrated circuit with a photodiode on the output.

This product enables to low current operation on 3.3V/5V power supply with high noise-tolerant CMR:50kV/us min. and high temperature operation up to Ta=125°C in logic interface circuit.

#### FEATURES

- Long creepage distance (8 mm MIN)
- High speed communication (15 Mbps)
- High temperature operation (-40 to +125°C)
- High common mode (dv/dt) tolerant (CM<sub>H</sub>, CM<sub>L</sub> =  $\pm 50 \text{ kV}/\mu \text{s}$  MIN.)
- High isolation voltage (BV = 5000 Vr.m.s.)
- Low input drive current (IFHL = 2.2 mA MAX.)
- Low voltage power supply operation (VDD = 2.7 V~5.5 V)
- Low pulse width distortion (PWD = 20 ns MAX.)
- Ordering number of tape product : RV1S9060ACCSP-10Yx#KC0 : 3000pcs/reel
- Pb free product
- Safety standards approval
  - UL : UL1577, Double protection
  - CSA : CAN/CSA-C22.2 No.62368-1, Reinforced insulation
  - VDE : DIN EN 60747-5-5 (Option)



TRUTH TABLE

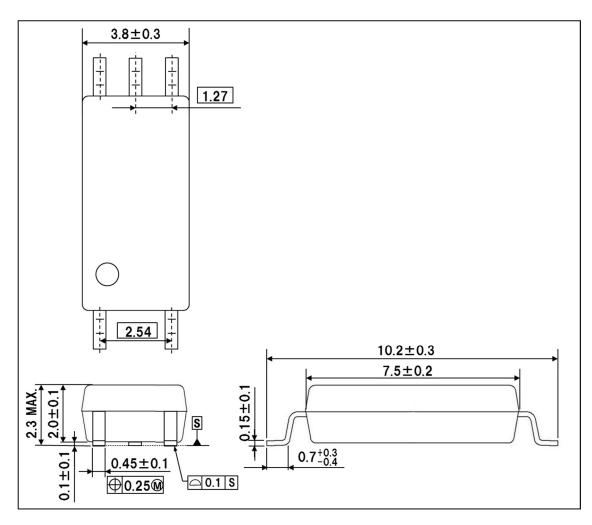
LED	OUTPUT
ON	L
OFF	Н

#### APPLICATIONS

- FA Network
- Measurement, Control Equipment (Inverter, AC Servo)



# PACKAGE DIMENSIONS (UNIT : mm)



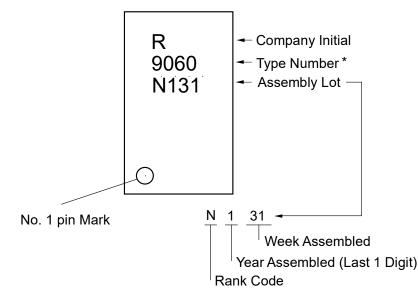
Weight: 0.119g (typ.)

#### PHOTOCOUPLER CONSTRUCTION

Parameter	MIN.
Air Distance	8.0 mm
Outer Creepage Distance	8.0 mm
Isolation Distance	0.15 mm



# MARKING EXAMPLE



\*Applicable type numbers are listed below.

\*1) RV1S 9060 ACCSP-10Yx

Marking type number. "RV1S" and "ACCSP-10Yx" are omitted from original type number.

# **ORDERING INFORMATION**

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number <sup>*1</sup>
RV1S9060ACCSP- 10YC	RV1S9060ACCSP -10YC#KC0	Pb-Free and Halogen Free	Embossed Tape 3 000 pcs/reel	Standard products (UL, CSA approved)	RV1S9060A
RV1S9060ACCSP- 10YV	RV1S9060ACCSP -10YV#KC0	(Ni/Pd/Au)	Embossed Tape 3 000 pcs/reel	UL, CSA, DIN EN 60747-5-5 approved	

Notes: \*1. For the application of the Safety Standard, following part number should be used.

#### ABSOLUTELY MAXIMUM RATINGS (T<sub>A</sub>=25°C, unless otherwise specified)

	Parameter	Symbol	Ratings	Unit
Diode	Forward Current *1	lF	20	mA
	Reverse Voltage	VR	5	V
Detector	Supply Voltage	VDD	6	V
	Output Voltage	Vo	6	V
	Output Current	lo	10	mA
	Power Dissipation *2	Pc	250	mW
Isolation V	/oltage <sup>*3</sup>	BV	5 000	Vr.m.s.
Operating Ambient Temperature		T <sub>A</sub>	-40 to +125	°C
Storage Temperature		T <sub>stg</sub>	-55 to +150	°C

Notes: 1. Reduced to 0.93mA/°C at T<sub>A</sub>=110°C or more

2. Reduced to 5.25mW/°C at T<sub>A</sub>=85°C or more

3. AC Voltage for 1minite at T\_A=25°C, RH=60% between input and output.

Pins 1-2 shorted together, 3-5 shorted together.



# RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Low Level forward voltage	VFL	0		0.8	V
High Level Forward Current	I <sub>FH</sub>	3		6	mA
Supply Voltage	Vdd	2.7		5.5	V

# ELECTRICAL CHARACTERISTICS

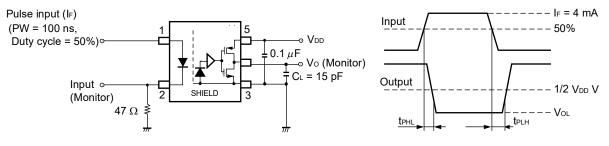
# (T<sub>A</sub>= -40 to +125°C, $V_{DD}$ = 2.7 to 5.5 V, unless otherwise specified)

	Parameter	Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit
Diode	Forward Voltage	VF	I <sub>F</sub> = 6 mA, T <sub>A</sub> = 25°C	1.4	1.55	1.7	V
	Reverse Current	IR	V <sub>R</sub> = 3 V, T <sub>A</sub> = 25°C			10	μA
	Terminal Capacitance	Ct	V <sub>F</sub> = 0 V, f = 1 MHz, T <sub>A</sub> = 25°C		30		pF
Detector	High Level Output Current	Iddh	I <sub>F</sub> = 0 mA		1.1	2	mA
	Low Level Output Current	IDDL	I <sub>F</sub> = 4mA		1.0	2	
	High Level Output Voltage	Vон	I <sub>O</sub> = −3.2mA, I <sub>F</sub> = 0 mA	Vdd-1.0	Vdd		V
			$I_0 = -20 \ \mu A, I_F = 0 \ mA$	Vdd-0.1	Vdd		
	Low Level Output Voltage	Vol	l₀ = 3.2mA, l⊧ = 4 mA		0.13	0.4	
			$I_0 = 20 \ \mu A, I_F = 4 \ mA$		0.001	0.1	
Coupled	Threshold Input Voltage (H to L)	IFHL	$V_O < 0.4 V$		1.2	2.2	mA
	Propagation Delay Time (H to L) <sup>*2</sup>	t <sub>PHL</sub>	I <sub>F</sub> = 4 mA ⇔ 0mA V <sub>DD</sub> = 3.3V,5 V		36	60	ns
	Propagation Delay Time (L to H) <sup>*2</sup>	t <sub>PLH</sub>	C∟ = 15 pF		38	60	
	Pulse Width Distortion <sup>*2</sup>	PWD			2	20	
	Propagation Delay Skew	t <sub>PSK</sub>				25	
	Rise Time	tr			5		
	Fall Time	t <sub>f</sub>			5		
	Common Mode	СМн	IF = 0 mA, VO > 4 V(VDD = 5V),	50	60		kV/μs
	Transient Immunity at		VO > 2.3 V(VDD = 3.3V),				
-	High Level Output*3		VCM=1.5kV, TA = 25°C				
	Common Mode	CM∟	I <sub>F</sub> = 4 mA,	50	60		
	Transient Immunity at		$V_O < 0.4 V(V_{DD} = 3.3V, 5V),$				
	Low Level Output* <sup>3</sup>		V <sub>CM</sub> =1.5kV, T <sub>A</sub> = 25°C				



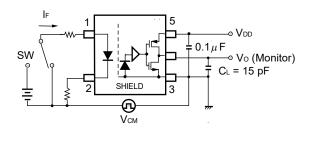
Note2: 1. Typical values at T<sub>A</sub> = 25°C

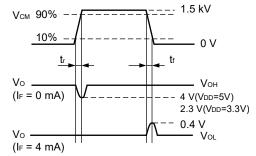
2. Test circuit for propagation delay time measurement

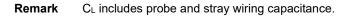


**Remark** C<sub>L</sub> includes probe and stray wiring capacitance.

3. Test circuit for common mode transient immunity measurement





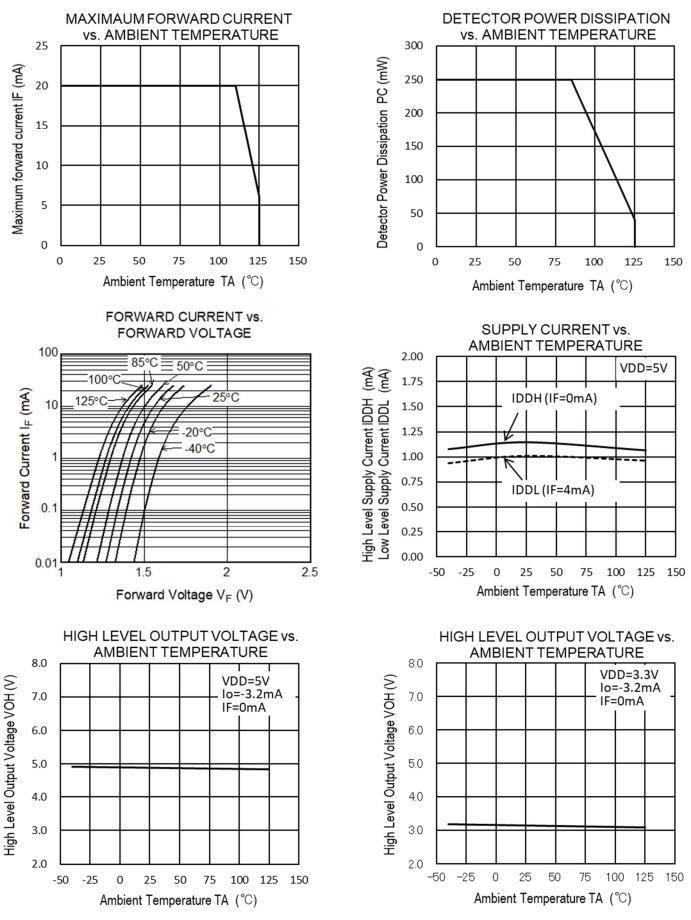


# USAGE CAUTIONS

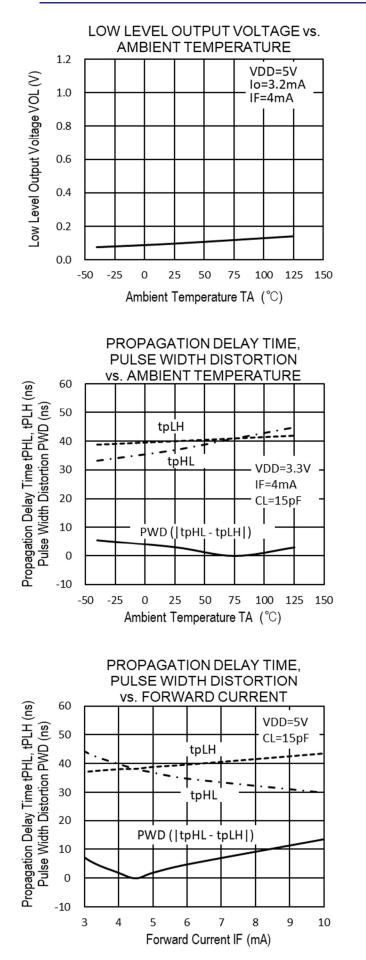
- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. By-pass capacitor of more than 0.1  $\mu$ F is used between V<sub>DD</sub> and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
- 3. Avoid storage at a high temperature and high humidity.







Remark The graphs indicate nominal characteristics.



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THRESHOLD INPUT CURRENT

vs. AMBIENT TEMPERATURE

VDD=5V

2.5

2.0

1.5

1.0

0.5

0.0

60

50

40

30

20

10

0

-10

-50

-25

0

-50

0

25

50

Ambient Temperature TA (°C)

PROPAGATION DELAY TIME,

PULSE WIDTH DISTORTION

vs. AMBIENT TEMPERATURE

PWD (|tpHL - tpLH|)

25

50

Ambient Temperature TA (°C)

75

75

100 125

VDD=5V

IF=4mA

CL=15pF

100 125 150

150

-25

tpLH

tpHL

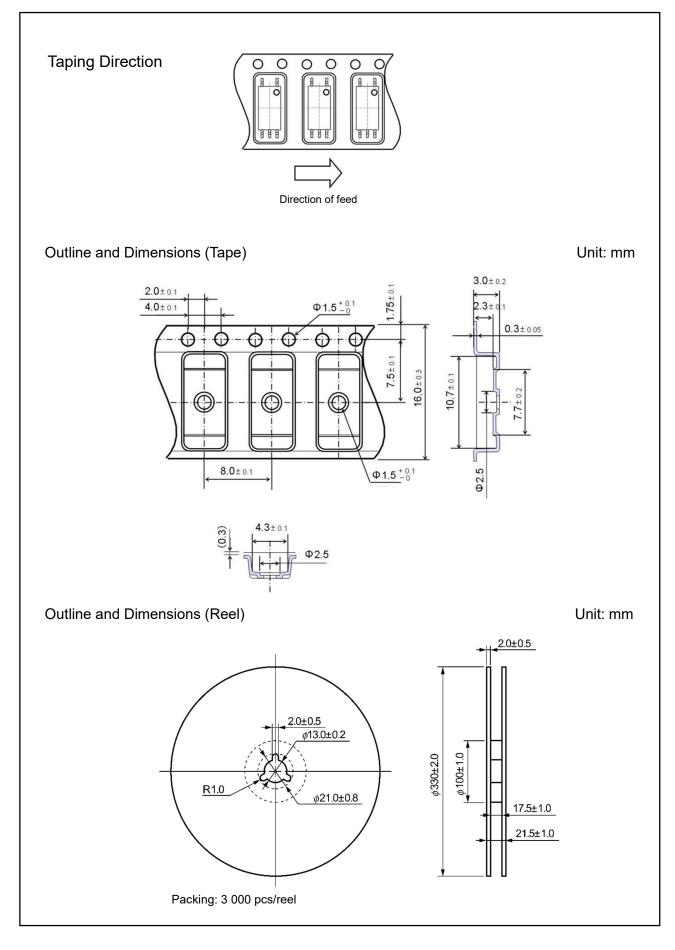
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Threshold Input Current IFHL (mA)

Propagation Delay Time tPHL, tPLH (ns)

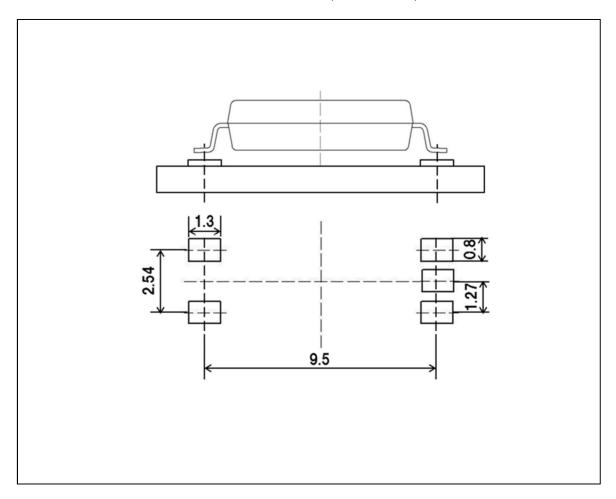
Pulse Width Distortion PWD (ns)

# TAPING SPECIFICATIONS (UNIT : mm)





# RECOMMENDED MOUNT PAD DIMENSIONS (UNIT : mm)





# NOTES ON HANDLING

- 1. Recommended soldering conditions
  - (1) Infrared reflow soldering
    - Peak reflow temperature
    - Time of peak reflow temperature
    - Time of temperature higher than 220°C
    - Time to preheat temperature from 120 to 180°C
    - Number of reflows
    - Flux

60 seconds or less 120±30 s

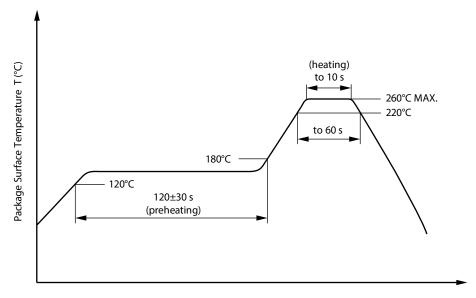
10 seconds or less

#### Three

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

260°C or below (package surface temperature)

#### Recommended Temperature Profile of Infrared Reflow



Time (s)

#### (2) Wave soldering

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
  - Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

#### (3) Soldering by Soldering Iron

- Peak Temperature (lead part temperature) 350°C or below
- Time (each pins)
  - Rosin flux containing small amount of chlorine
  - (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

3 seconds or less

- (a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead
- (b) Please be sure that the temperature of the package would not be heated over 100°C

#### (4) Cautions

Flux

- Flux Cleaning
  - Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
- Do not use adhesives or coating materials including halogens to fix this device.
- 2. Cautions regarding noise

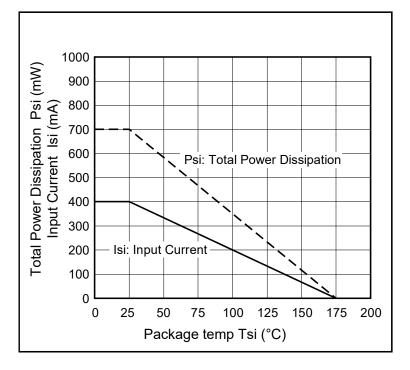
Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.



# SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

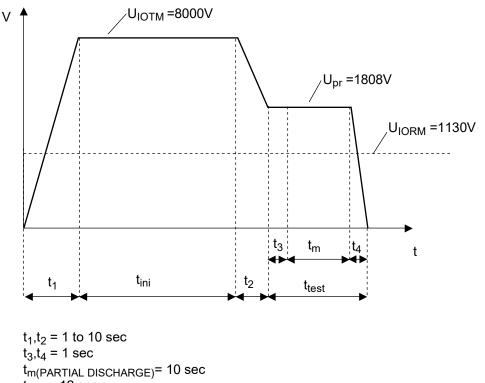
Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/125/21	
Dielectric strength			
maximum operating isolation voltage	UIORM	1 130	V <sub>peak</sub>
Test voltage (partial discharge test, procedure a for type test and random test)	Upr	1 808	V <sub>peak</sub>
$U_{pr}$ = 1.6 × $U_{IORM.}$ , $P_d < 5 \text{ pC}$			
Test voltage (partial discharge test, procedure b for all devices)	Upr	2 119	V <sub>peak</sub>
$U_{pr}$ = 1.875 × $U_{IORM.}$ , $P_d < 5 \ pC$			
Highest permissible overvoltage	UIOTM	8 000	V <sub>peak</sub>
Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11))	CTI	400	
Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		II	
Storage temperature range	T <sub>stg</sub>	–55 to +150	°C
Operating temperature range	TA	-40 to +125	°C
Isolation resistance, minimum value			
$V_{IO} = 500 \text{ V dc} \text{ at } T_A = 25^{\circ}\text{C}$	Ris MIN.	10 <sup>12</sup>	Ω
V <sub>IO</sub> = 500 V dc at T <sub>A</sub> MAX. at least 100°C	Ris MIN.	10 <sup>11</sup>	Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal			
derating curve)			
Package temperature	Tsi	175	°C
Current (input current I <sub>F</sub> , Psi = 0)	lsi	400	mA
Power (output or total power dissipation)	Psi	700	mW
Isolation resistance			
$V_{IO}$ = 500 V dc at $T_A$ = Tsi	Ris MIN.	10 <sup>9</sup>	Ω

# Dependence of maximum safety ratings with package temperature



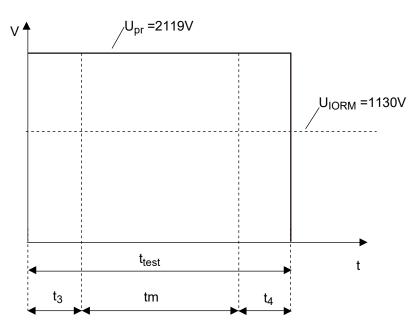






 $t_{test} = 12 \text{ sec}$  $t_{ini} = 60 \text{ sec}$ 





 $t_{3}, t_{4} = 0.1 \text{ sec}$  $t_{m}(\text{PARTIAL DISCHARGE}) = 1.0 \text{ sec}$  $t_{test} = 1.2 \text{ sec}$ 



Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
	<ol> <li>Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.</li> </ol>
	2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
	Do not burn, destroy, cut, crush, or chemically dissolve the product.
	• Do not lick the product or in any way allow it to enter the mouth.

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